

MBR20100CT, MBRF20100CT & MBRB20100CT Series

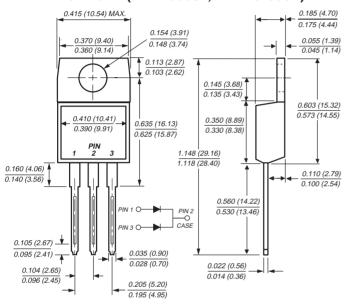
New Product

Vishay Semiconductors formerly General Semiconductor

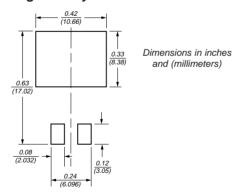
Dual High-Voltage Schottky Rectifiers



TO-220AB (MBR2090CT, MBR20100CT)



Mounting Pad Layout TO-263AB

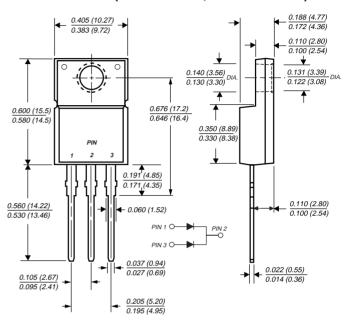


Features

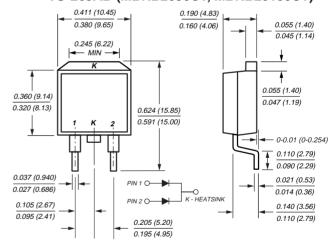
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

Reverse Voltage 90 to 100V Forward Current 20A

ITO-220AB (MBRF2090CT, MBRF20100CT)



TO-263AB (MBRB2090CT, MBRB20100CT)



Mechanical Data

Case: JEDEC TO-220AB, ITO-220AB & TO-263AB mold-

ed plastic body

Terminals: Plated leads, solderable per

MIL-STD-750, Method 2026

Polarity: As marked **Mounting Position:** Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08 oz., 2.24 g

Document Number 88672 02-Jul-02

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Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR2090CT	MBR20100CT	Unit
Maximum repetitive peak reverse voltage	VRRM	90	100	V
Working peak reverse voltage	VRWM	90	100	V
Maximum DC blocking voltage	V _D C	90	100	V
Maximum average forward rectified current $Total \ device$ at $T_C = 133^{\circ}C$ $Per \ leg$	lf(AV)	20 10		А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) per leg	IFSM	150		А
Peak repetitive reverse current per leg at $t_p = 2\mu s$, 1KHz	I _{RRM}	0.5		А
Voltage rate of change (rated V _R)	dv/dt	10,000		V/µs
Operating junction and storage temperature range	TJ, TSTG	-65 to +150		°C
RMS Isolation voltage (MBRF type only) from terminals to heatsink with $t=1$ second, RH $\leq 30\%$	Visol	4500 ⁽¹⁾ 3500 ⁽²⁾ 1500 ⁽³⁾		V

Electrical Characteristics (TC = 25°C unless otherwise noted)

Parameter		Symbol	Value	Unit
Maximum instantaneous forward voltage per leg at ⁽⁴⁾ :	$I_F = 10A, T_C = 25^{\circ}C$ $I_F = 10A, T_C = 125^{\circ}C$ $I_F = 20A, T_C = 25^{\circ}C$ $I_F = 20A, T_C = 125^{\circ}C$	VF	0.80 0.65 0.95 0.75	V
Maximum reverse current per at working peak reverse voltage		lR	100 6.0	μA mA

Thermal Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR	MBRF	MBRB	Unit
Typical thermal resistance per leg	R⊕JA R⊕JC	60	— 3.5	60	°C/W

(1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset

(2) Clip mounting (on case), where leads do overlap heatsink
(3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
(4) Pulse test: 300μs pulse width, 1% duty cycle

Ordering Information

Product	Case	Package Code	Package Option
MBR2090CT, MBR20100CT	TO-220AB	45	Anti-Static tube, 50/tube, 2K/carton
MBRF2090CT, MBRF20100CT	ITO-220AB	45	Anti-Static tube, 50/tube, 2K/carton
MBRB2090CT, MBRB20100CT	TO-263AB	31 45 81	13" reel, 800/reel, 4.8K/carton Anti-Static tube, 50/tube, 2K/carton Anti-Static 13" reel, 800/reel, 4.8K/carton

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Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

Resistive or Inductive Load

Resistive or Inductive Load

12

0

0

50

100

150

Case Temperature (°C)

Fig. 3 - Typical Instantaneous **Forward Characteristics** 50 IF - Instantaneous Forward Current (A) 20 150°C 10 100°C 5.0 3.0 = 25°C 1.0 0.5 0.1 0.2 0.3 0.4 0.5 0.6 0.7 Instantaneous Forward Voltage (V)

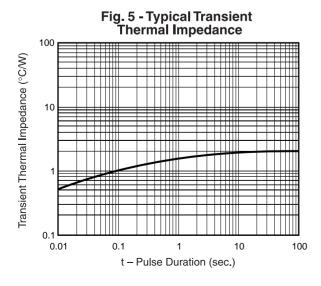


Fig. 2 - Maximum Non-Repetitive Peak
Forward Surge Current

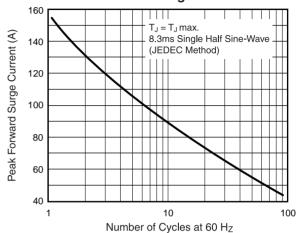
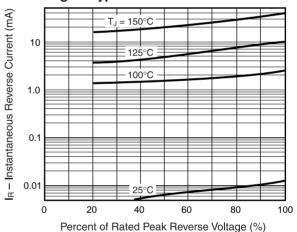


Fig. 4 - Typical Reverse Characteristics



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